

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	23	("20020058394"   "20020061646"   "20020192949"   "20030073302"   "6265321"   "6346484"   "6358813"   "6451712"   "6495479"   "6506660"   "6509623").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L2	0	L1 and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L3	0	L1 and sublithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L4	1232696	interconnect\$3 or plug and sub adj lithograph \$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L5	366	(interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L6	300	(interconnect\$3 or plug) and (sub adj lithograph\$2 and etch\$ with (insulat\$3 or dielectric or oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L7	0	L6 and (sublithograph \$2 with feature with sidewall)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47

L8	11	L6 and (sublithograph \$2 with sidewall)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L9	0	L8 and nano adj column	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L10	5	L6 and nano adj column	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L11	1232709	L1 L2 L3 L4 L5 L6 L7 L8 L9 L10	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:47
L12	366	(interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:48
L13	330	12 and (insulator or dielectric or oxide or nitride)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:49
L14	4	12 and (insulator or dielectric or oxide or nitride) with etch\$3 with sublithographic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:49
L15	35	12 and (insulator or dielectric or oxide or nitride) with etch\$3 with sub adj lithographic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:50
L16	31	15 and sidewall	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:50

L17	5	16 and capping	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:50
L18	1676	438/618.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:54
L19	562	438/703.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:55
L20	918	438/623.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:55
L21	367	438/736.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:55
L22	2	18 and (interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:55
L23	1	19 and (interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:55
L24	2	20 and (interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:56
L25	3	21 and (interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:56

L26	1	22 and (insulator or dielectric or oxide or nitride) with etch\$3 with sub adj lithographic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:56
L27	1	23 and (insulator or dielectric or oxide or nitride) with etch\$3 with sub adj lithographic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:56
L28	1	24 and (insulator or dielectric or oxide or nitride) with etch\$3 with sub adj lithographic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:56
L29	1	25 and (insulator or dielectric or oxide or nitride) with etch\$3 with sub adj lithographic	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2008/05/05 21:56
S1	8037	pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:13
S2	65	S1 and vertical with pull adj up and pull adj down	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:45
S3	1519	pull adj up and pull adj down with transistor and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:46
S4	96	S3 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:15
S5	2	S4 and common adj body	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:46

S6	12	S3 and common adj source and pass adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:54
S7	3	S3 and common adj source and pass adj gate and diffusion	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:48
S8	10943	"12" and common adj channel or common adj body	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:54
S9	2	S6 and ((common adj channel) or (common adj body))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 16:55
S10	2	"6788112" and (common)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:10
S11	705	327/51.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:10
S12	353	327/57.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:11
S13	1460	257/368.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:12
S14	412	257/393.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:12

S15	936	257/379.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:12
S16	57	S11 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:39
S17	38	S12 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:13
S18	19	S13 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:13
S19	15	S14 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:13
S20	20	S15 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:14
S21	14	S16 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:14
S22	8	S17 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:14
S23	12	S18 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:14

S24	14	S19 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:14
S25	16	S20 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:14
S27	1	S22 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S28	1	S23 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:15
S29	2	S24 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:50
S30	2	S25 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/17 17:15
S31	706	327/51.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:38
S32	57	S31 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:38
S33	14	S32 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40

S34	2	S33 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40
S35	516	327/52.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:39
S36	318	327/55.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:39
S37	45	S35 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40
S38	46	S36 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40
S39	14	S37 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40
S40	16	S38 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40
S41	3	S39 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:40
S42	9	S40 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:41



S43	185350	S40 and "V.sub.t" or "Vt" or threshold adj voltage	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:41
S44	2	S41 and ("V.sub.t" or "Vt" or (threshold adj voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:41
S45	8	S42 and ("V.sub.t" or "Vt" or (threshold adj voltage))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:44
S46	0	S45 and common adj body	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:42
S47	0	S45 and pass adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:44
S48	1	S42 and pass adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S49	354	327/57.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S50	39	S49 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S51	8	S50 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45

S52	1	S51 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S53	1	S52 and pass adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S54	936	257/379.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S55	20	S54 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S56	16	S55 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S57	2	S56 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:45
S58	1	S57 and pass adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:46
S59	413	257/393.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:50
S60	15	S59 and pull adj up and pull adj down with transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:50

S61	14	S60 and SRAM	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:50
S62	2	S61 and common adj source	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:51
S63	1	S62 and pass adj gate	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:50
S64	1	S61 and (common adj (body or channel))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:51
S65	1	S62 and (common adj (body or channel))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:52
S66	19980	Hsu.in.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:52
S67	56	S66 and pull adj up adj transistor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:52
S68	1	S66 and pull adj up adj transistor and common adj body	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/18 16:53

S69	23	("20020058394"   "20020061646"   "20020192949"   "20030073302"   "6265321"   "6346484"   "6358813"   "6451712"   "6495479"   "6506660"   "6509623").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:17
S70	0	S69 and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:11
S71	0	S69 and sublithograph \$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:11
S72	1100092	interconnect\$3 or plug and sub adj lithograph \$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:11
S73	264	(interconnect\$3 or plug) and sub adj lithograph\$2	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:11
S74	218	(interconnect\$3 or plug) and (sub adj lithograph\$2 and etch\$ with (insulat\$3 or dielectric or oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:12
S75	0	S74 and (sublithograph \$2 with feature with sidewall)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:13
S76	8	S74 and (sublithograph \$2 with sidewall)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:14

S77	0	S76 and nano adj column	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:14
S78	1	S74 and nano adj column	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/07/19 14:14

**5/5/08 9:57:05 PM****C:\Documents and Settings\LSchillinger\My Documents\EAST\Workspaces\10707996.wsp**